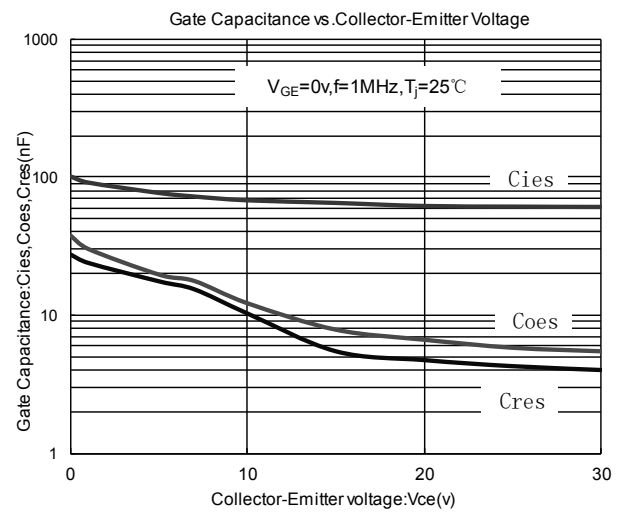
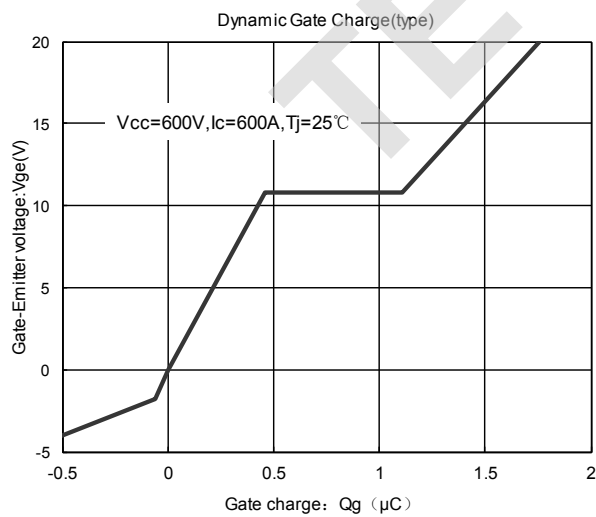
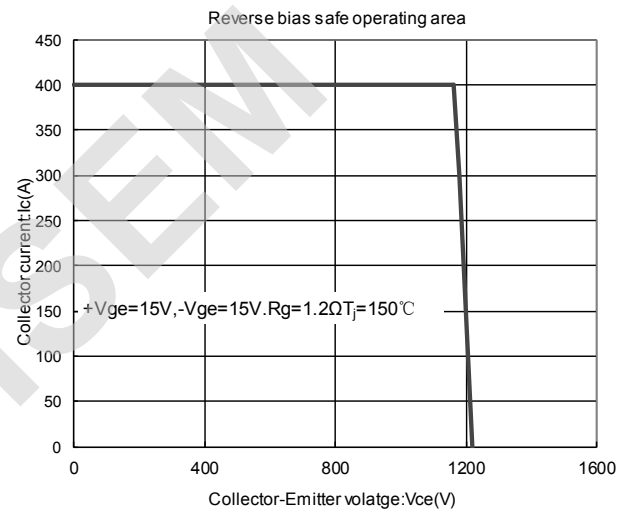
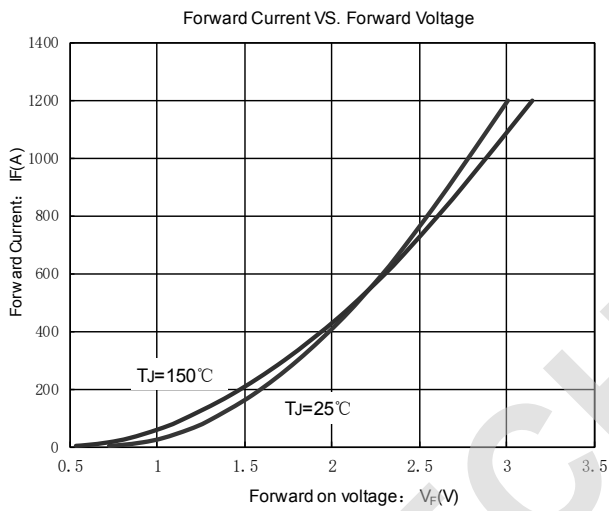
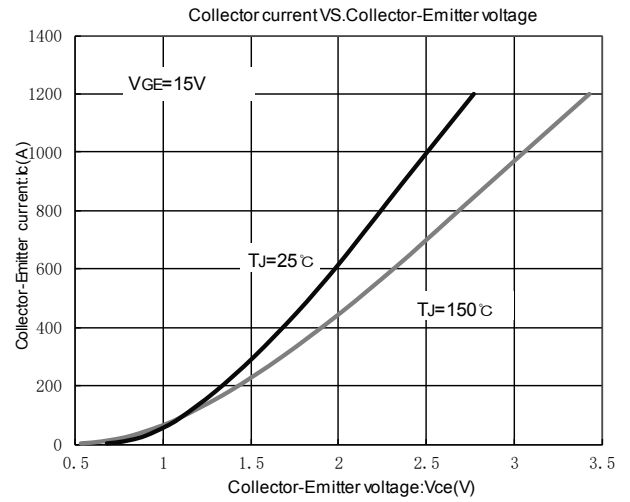
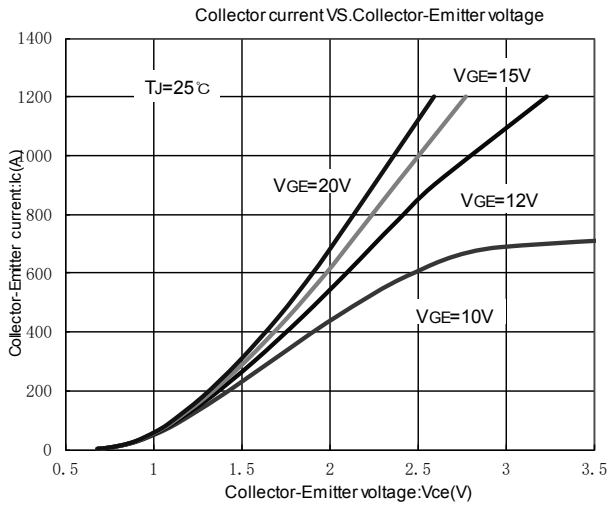
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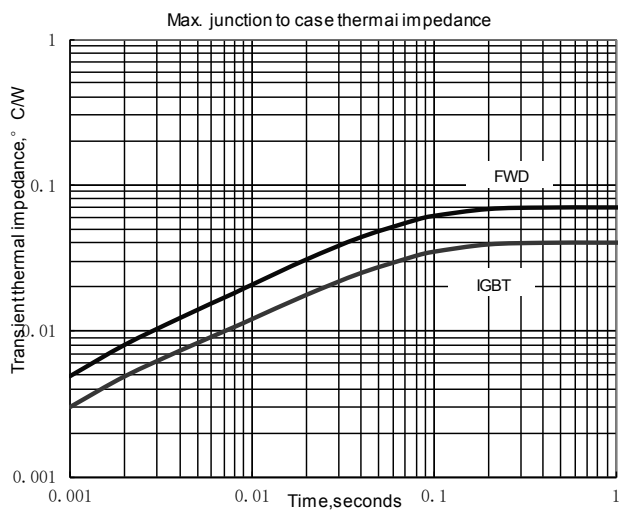
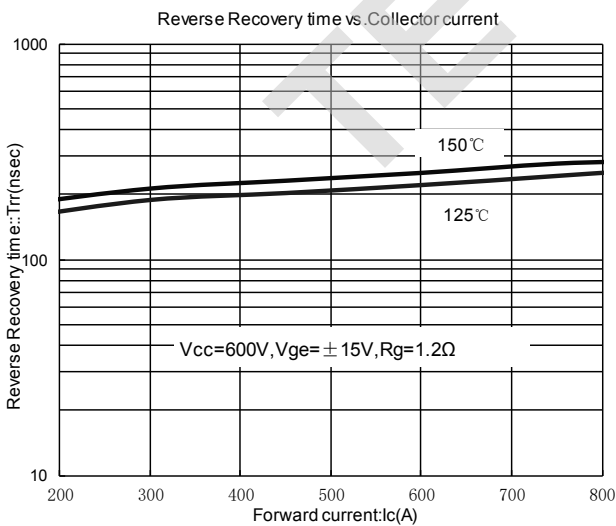
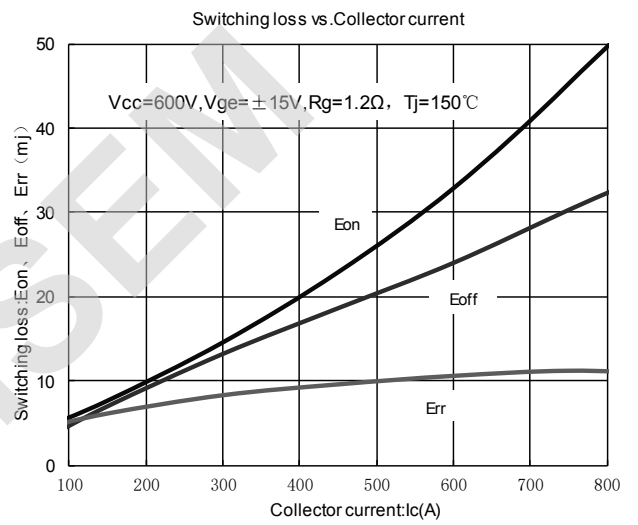
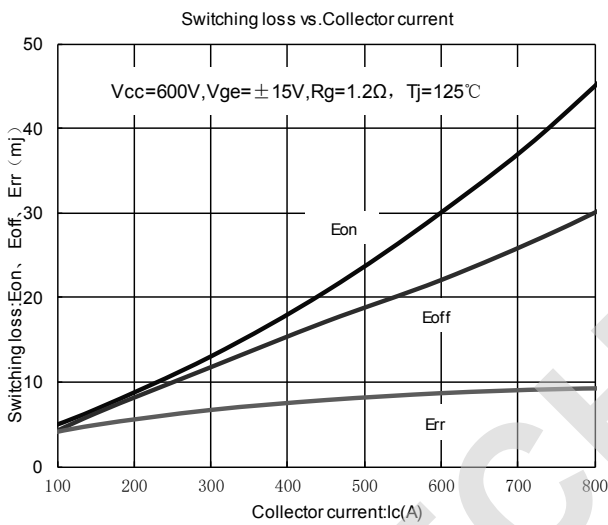
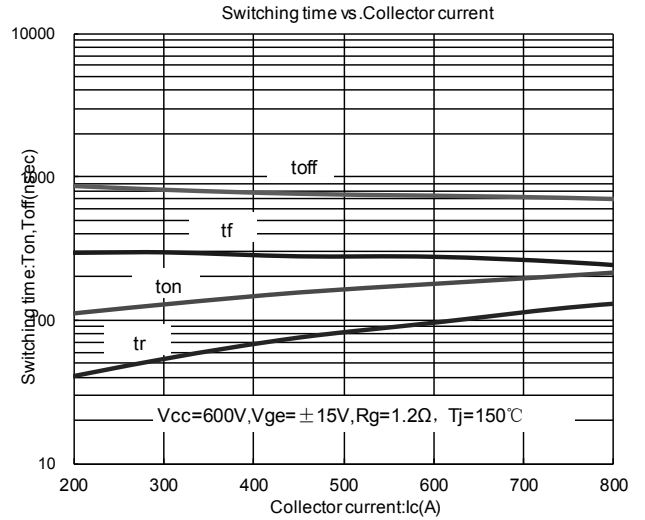
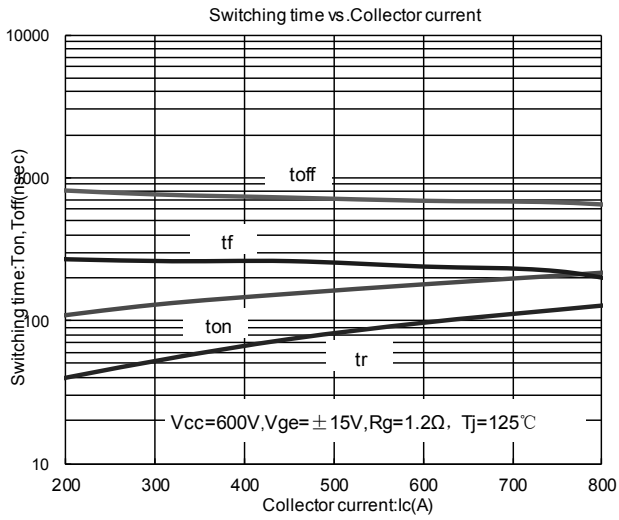
- Low V_{CEsat}
- Standard Housing

Typical Applications :

- Motor Drive
- Servo Drive
- Uninterruptible Power Supply System
- Wind Turbines
- High Power Converters

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	VALUE			UNIT
			Min	Type	Max	
V_{CES}	Collector-Emitter voltage	$T_j=25^\circ\text{C}$			1250	V
V_{GES}	Gate-Emitter voltage	$T_j=25^\circ\text{C}$			± 30	V
I_C	Collector current	Continuous@ $T_c=100^\circ\text{C}$			600	A
I_{CP}		$T_P=1\text{ms}$			1200	A
P_C	Collector power dissipation	$T_j=150^\circ\text{C}$, 1 device			3750	W
T_j	Junction temperature	/			175	$^\circ\text{C}$
T_{stg}	Storage temperature	/	-40		125	$^\circ\text{C}$
V_{iso}	Isolation between terminal and copper base	$T_j=25^\circ\text{C}$, AC: 1minute	3000			V
Screw torque	Mounting(M6)	/	3.0	4.5	6.0	N·m
	Terminals(M6)	/	2.5	4.0	5.0	N·m
I_{CES}	Zero gate voltage collector current	$T_j=25^\circ\text{C}$, $V_{CE}=1200\text{V}$, $V_{GE}=0\text{V}$			1.5	mA
I_{GES}	Gate-Emitter leakage current	$T_j=25^\circ\text{C}$, $V_{CE}=0\text{V}$, $V_{GE}=\pm 20\text{V}$			± 0.5	μA
$V_{GE(th)}$	Gate-Emitter threshold voltage	$T_j=25^\circ\text{C}$, $V_{CE}=20\text{V}$, $I_C=150\text{mA}$	4.5		8.5	V
$V_{CE(sat)}$	Collector-Emitter saturation voltage	$T_j=25^\circ\text{C}$, $V_{GE}=15\text{V}$, $I_C=600\text{A}$		1.96	2.16	V
		$T_j=125^\circ\text{C}$, $V_{GE}=15\text{V}$, $I_C=600\text{A}$		2.25		V
		$T_j=150^\circ\text{C}$, $V_{GE}=15\text{V}$, $I_C=600\text{A}$		2.33		V
C_{ies}	Input capacitance	$T_j=25^\circ\text{C}$, $V_{CE}=10\text{V}$, $V_{GE}=0\text{V}$, $f=1\text{MHz}$		66.6		nF
t_{on}	Turn-on time	$T_j=150^\circ\text{C}$, $V_{CC}=600\text{V}$, $I_C=600\text{A}$, $V_{GE}=\pm 15\text{V}$, $R_g=1.2\Omega$, Inductive load		180		ns
t_r				95		ns
t_{off}	Turn-off time	$T_j=150^\circ\text{C}$, $V_{CC}=600\text{V}$, $I_C=600\text{A}$, $V_{GE}=\pm 15\text{V}$, $R_g=1.2\Omega$, Inductive load		730		ns
t_f				270		ns
t_{sc}	Short circuit withstand time	$T_j=150^\circ\text{C}$, $V_{CC}=720\text{V}$, $V_{GE}=\pm 15\text{V}$, $R_g=1.2\Omega$	10			μs
V_F	Forward on voltage	$T_j=25^\circ\text{C}$, $I_F=600\text{A}$		2.28	2.48	V
		$T_j=125^\circ\text{C}$, $I_F=600\text{A}$		2.26		V
		$T_j=150^\circ\text{C}$, $I_F=600\text{A}$		2.30		V
t_{rr}	Reverse recovery time	$T_j=125^\circ\text{C}$, $I_F=600\text{A}$		220		ns
		$T_j=150^\circ\text{C}$, $I_F=600\text{A}$		250		ns
$R_{th(j-c)}$	Thermal resistance(1 device)	IGBT			0.04	$^\circ\text{C/W}$
		FWD			0.07	$^\circ\text{C/W}$
$R_{th(c-f)}$	Contact thermal resistance (1 device)	With thermal compound		0.050		$^\circ\text{C/W}$
W_t	Weight				345	g
Outline		465H3				





Outline & Circuit Diagram

